## NSN 5962-01-252-7008

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View Online at https://aerobasegroup.com/nsn/5962-01-252-7008 **Body Length:** Between 0.750 inches and 0.810 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.180 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **End Application:** Test set, guided missile an/dsm-156a **Features Provided:** Hermetically sealed and schottky and programmable and electrostatic sensitive **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 35.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a

Demilitarization:

**Unit Of Measure:** 

Yes - demil/mli

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